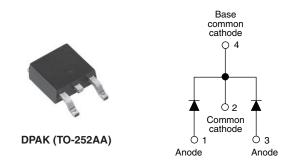
Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 6 A



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PRIMARY CHARACTERISTICS									
I _{F(AV)}	2 x 6 A								
V _R	30 V								
V _F at I _F	0.37 V								
I _{RM}	58 mA at 125 °C								
T _J max.	150 °C								
E _{AS}	10 mJ								
Package	DPAK (TO-252AA)								
Circuit configuration	Common cathode								

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long RoHS
 term reliability
- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-12CWQ03FN-M3 surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	12	А						
V _{RRM}		30	V						
I _{FSM}	$t_p = 5 \ \mu s \ sine$	320	А						
V _F	6 A _{pk} , T _J = 125 °C (per leg)	0.37	V						
Тј	Range	-55 to +150	°C						

VOLTAGE RATINGS								
PARAMETER SYN		VS-12CWQ03FN-M3	UNITS					
Maximum DC reverse voltage	V _R	30	V					
Maximum working peak reverse voltage	V _{RWM}	30	v					

ABSOLUTE MAXIMUM RATINGS										
PARAMETER		SYMBOL	TEST CONDI	TIONS	VALUES	UNITS				
Maximum average forward	per leg	Investigation of the second se	50 % duty avala at $T_{\rm c} = 135$ °C	rootopgular wavoform	6	А				
current, see fig. 5	per device	I _{F(AV)}	50 % duty cycle at T_{C} = 135 °C, rectangular waveform		12	A				
Maximum peak one cycle non-repetitive surge current per leg, see fig. 7			5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	320	А				
		IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	130	~				
Non-repetitive avalanche ene	ergy per leg	E _{AS}	$T_{J} = 25 \text{ °C}, I_{AS} = 2.0 \text{ A}, L = 5 \text{ mH}$		10	mJ				
Repetitive avalanche current	per leg	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximu		2.0	А				

Revision: 04-Jan-18

Document Number: 93285

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS				
Maximum forward voltage drop per leg See fig. 1		6 A	T _{.1} = 25 °C	0.47					
	V _{FM} ⁽¹⁾	12 A	1j=25 C	0.55	v				
	¥FM ("	6 A	T _{.1} = 125 °C	0.37					
		12 A	1j = 125 0	0.49					
Maximum reverse	. (1)	T _J = 25 °C		3					
leakage current per leg See fig. 2	I _{RM} ⁽¹⁾	I_{RM} ⁽¹⁾ $T_{J} = 125 \ ^{\circ}C$ $V_{R} = Rated V_{R}$		58	mA				
Threshold voltage	V _{F(TO)}	T _{.1} = T _{.1} maximum	T. T. maximum		V				
Forward slope resistance	r _t	ij = ij maximum	21.66	mΩ					
Typical junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range	590	pF					
Typical series inductance per leg	L _S	Measured lead to lead 5 m	nm from package body	5.0	nH				

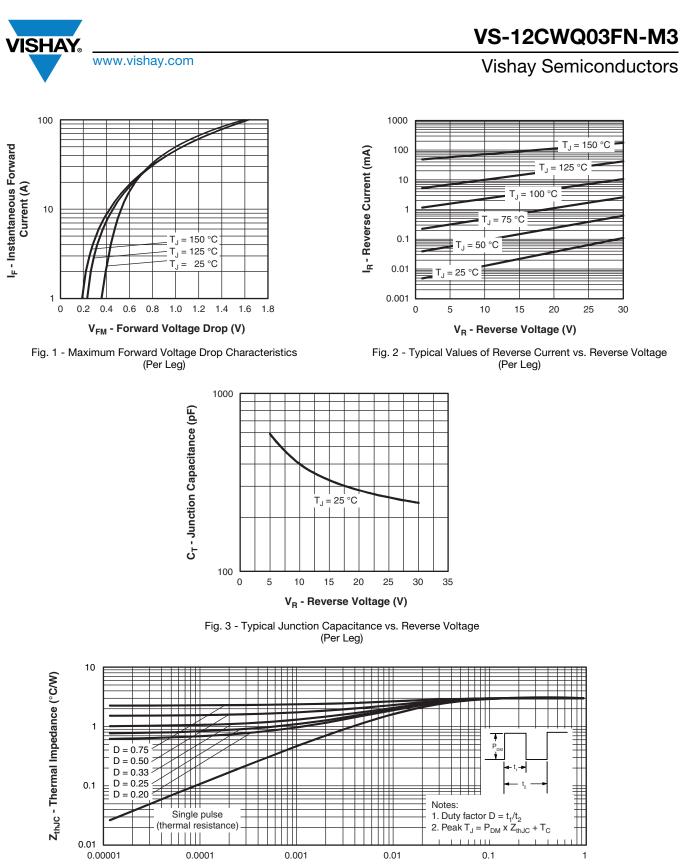
Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T _J ⁽¹⁾ , T _{Stg}		-55 to +150	°C				
Maximum thermal resistance,	per leg	R _{thJC}	DC operation	3.0	°C/W				
junction to case	per device	nthJC	See fig. 4	1.5	0/ 10				
Approximate weight				0.3	g				
				0.01	oz.				
Marking device			Case style DPAK (TO-252AA)	12CW0	Q03FN				

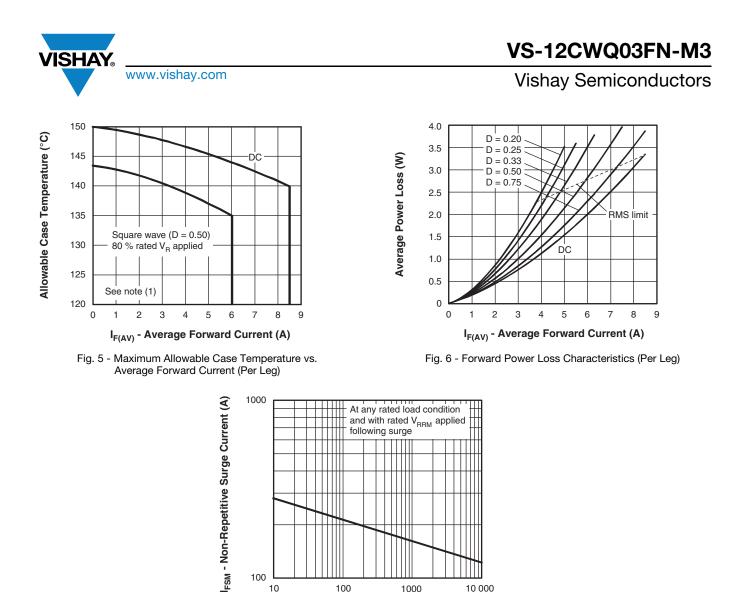
Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



t₁ - Rectangular Pulse Duration (s)

Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)



Note

- (1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

100 10

100

t_p - Square Wave Pulse Duration (μs) Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

1000

10 000

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ORDERING INFORMATION TABLE

Device code	VS-	12	с	w	Q	03	FN	TRL	-M3
		2	3	4	5	6	7	8	9
	3 4 5 7	- Cur - Cer - Pac W = - Sch - Volt	rent rati nter tap kage id DPAK nottky "C tage rati = TO-25	2" series ng (03 = 52AA	A) ration	oduct			
	8	• TI	-	be and ree e and re		oriented	4)		
	9	- Env	rironmer	be and rontal digit	:			4	

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-12CWQ03FN-M3	75	3000	Antistatic plastic tube							
VS-12CWQ03FNTR-M3	2000	2000	13" diameter reel							
VS-12CWQ03FNTRL-M3	3000	3000	13" diameter reel							
VS-12CWQ03FNTRR-M3	3000	3000	13" diameter reel							

LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?95627							
Part marking information	www.vishay.com/doc?95176							
Packaging information	www.vishay.com/doc?95033							
SPICE model	www.vishay.com/doc?96476							





D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES		ES NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC			
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410			
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070			
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.			
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC			
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3		
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040			
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2		
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°			
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°			
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°			

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC[®] outline TO-252AA



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